


Helping Customers Innovate, Improve & Grow



## Description

The VS-708 is a Voltage Controlled SAW Oscillator that operates at the fundamental or a fraction of the internal SAW filter frequency. The SAW component is a high-Q Quartz device that enables the circuit to achieve low phase jitter performance over a wide operating temperature range. The oscillator is housed in a hermetically sealed leadless surface mount package and offered on tape and reel. It has a tri-state Output Enable function that provides one of three conditions: Outputs Enabled, Outputs Set, or Outputs Disabled.

## Features

- Industry Standard Package: 5.0 x 7.0 x 1.8 mm<sup>3</sup>
- Output Frequencies: 600 MHz to 2.3 GHz
- 5<sup>th</sup> Generation ASIC Technology for Low Jitter  
55 fs-rms ( $f_N = 1.8$  GHz, 12 kHz to 20 MHz)
- Absolute Pull Range:  $\pm 50$  ppm
- Supply Voltage: 3.3 V
- LVDS Compatible Outputs ( $f_N < 1.2$  GHz)
- Differential or SE Sinewave Outputs ( $f_N \geq 1.2$  GHz)
- Tri-State Output Enable (OE / OS / OD)
- Compliant to EU RoHS 6 Directive 

## Applications

- High Speed Data Converters (ADC / DAC)
- Optical Transport Networks (40G / 100G / 200G / 400G)
- Wireless Communication
- Cable Modem Termination Systems (DOCSIS)

## Block Diagram

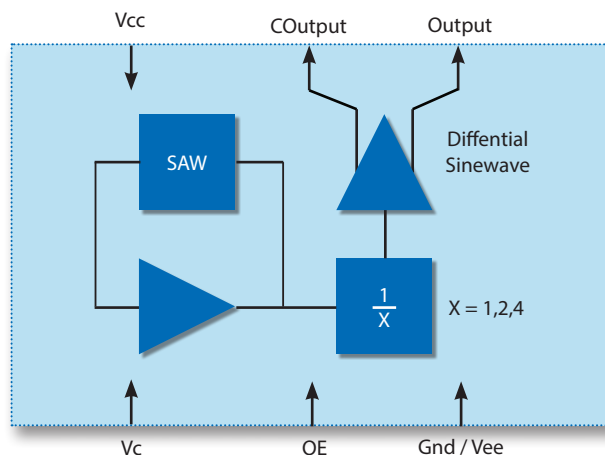


Figure 1. Functional block diagram

## Performance Specifications

Electrical Performance						
Parameter	Symbol	Minimum	Typical	Maximum	Units	Notes
<b>Frequency</b>						
Nominal Frequency	$f_N$	600		2300	MHz	1,3
Absolute Pull Range	APR	$\pm 50$			ppm	1,3,4
Gain Transfer	$K_V$		+200		ppm/V	4
Temperature Stability	$f_{STAB}$		$\pm 50$		ppm	1
<b>Supply</b>						
Voltage ( $\pm 10\%$ )	$V_{CC}$	2.97	3.3	3.63	V	3
Current (Typical 50 $\Omega$ Load)	$I_{EE}$		80		mA	2,3
<b>Outputs (<math>f_N &lt; 1.2</math> GHz)</b>						
LVDS						
Output Power (0.7 GHz to 0.9 GHz)		-1.5			dBm	2,3
Output Power (0.9 GHz to 1.2 GHz)		-2			dBm	2,3
<b>Outputs (<math>f_N \geq 1.2</math> GHz)</b>						
Single Ended Sinewave						
Output Power ( $> 1.20$ GHz to $< 1.90$ GHz)			-4		dBm	
Output Power ( $\geq 1.91$ GHz to $< 2.30$ GHz)			-6		dBm	
Differential Sinewave						
Differential Swing ( $f_N = 1.2$ GHz)			1100		mV	
Differential Swing ( $f_N = 1.8$ GHz)			900		mV	
Differential Swing ( $f_N = 2.1$ GHz)			800		mV	
Differential Swing ( $f_N = 2.3$ GHz)			650		mV	
Subharmonics			$< -85$		dBc	
Harmonics ( $f_N > 2.1$ GHz)			$< -25$		dBc	
<b>Outputs (600 MHz <math>&lt; f_N &lt; 2.3</math> GHz)</b>						
Spurious Suppression (Non-Harmonic)		85	90		dBc	
Symmetry	SYM	45	50	55	%	3
Jitter						
(10 kHz to 40 MHz)	$\Phi_J$		70		fs-rms	
(12 kHz to 20 MHz)	$\Phi_J$		55		fs-rms	
<b>Control Voltage</b>						
Control Voltage	$V_C$	0.3		3.0	V	3
Modulation Bandwidth	BW		50		kHz	
<b>Operating Temperature</b>	$T_{OP}$	-40		+85	$^{\circ}C$	1,3
<b>Package Size</b>		5.0 x 7.0 x 1.8			mm <sup>3</sup>	

### Notes:

1. See Standard Frequencies and Ordering Information (Pg 6).
2. Output power levels degrade linearly over the whole frequency range. Given values are worst case values for each frequency range.
3. Parameters are tested at ambient temperature with test limits guard-banded for specified operating temperature.
4. Tested with  $V_C = 0.3V$  to  $3.0V$ .
5. The  $V_C$  Model is described below (Fig 1).

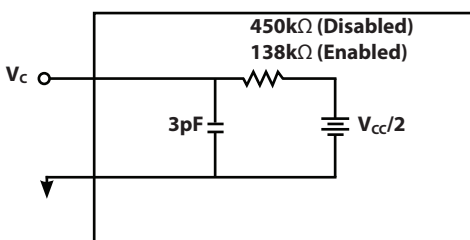


Figure 1.  $V_C$  Model - Outputs Enabled / Disabled

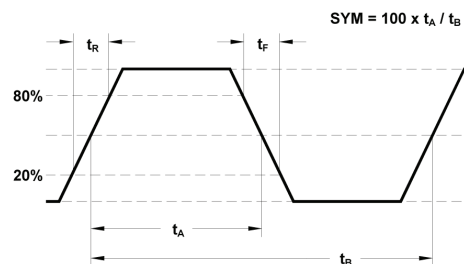


Figure 2. Waveform

# Absolute Maximum Ratings

Absolute Maximum Ratings			
Parameter	Symbol	Ratings	Unit
Power Supply	$V_{CC}$	0 to 6	V
Voltage Control Range	$V_C$	0 to $V_{CC}$	V
Output Enable	OE	0 to $V_{CC}$	V
Storage Temperature	$T_{STR}$	-55 to 125	$^{\circ}C$
Soldering Temperature/Duration	$T_{PEAK}/t_P$	260 / 40	$^{\circ}C/s$

Stresses in excess of the absolute maximum ratings can permanently damage the device. Also, exposure to these absolute maximum ratings for extended periods may adversely affect device reliability. Functional operation is not implied at these or any other conditions in excess of those represented in the operational sections of this datasheet. Permanent damage is also possible if any device input ( $V_C$  or OE) draws >100 mA.

## Performance Characteristics

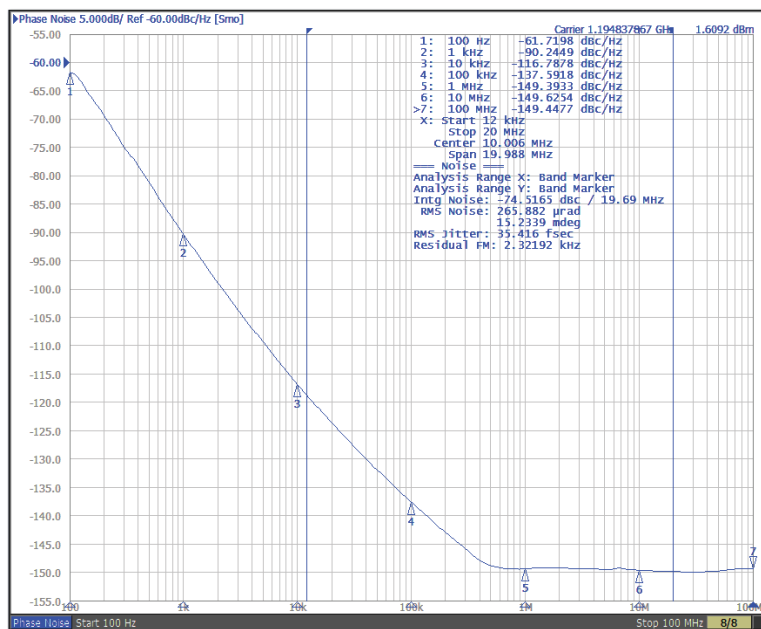


Figure 3. Performance Characteristics @ 1.2 GHz

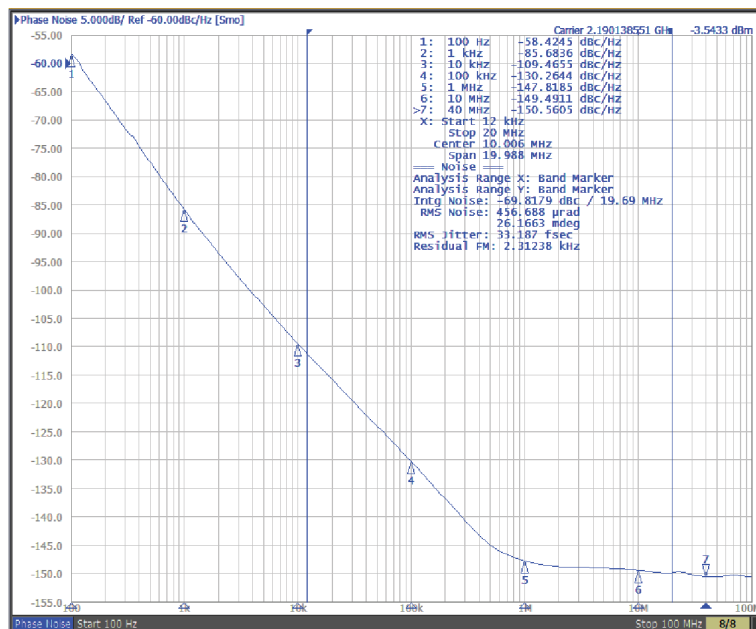
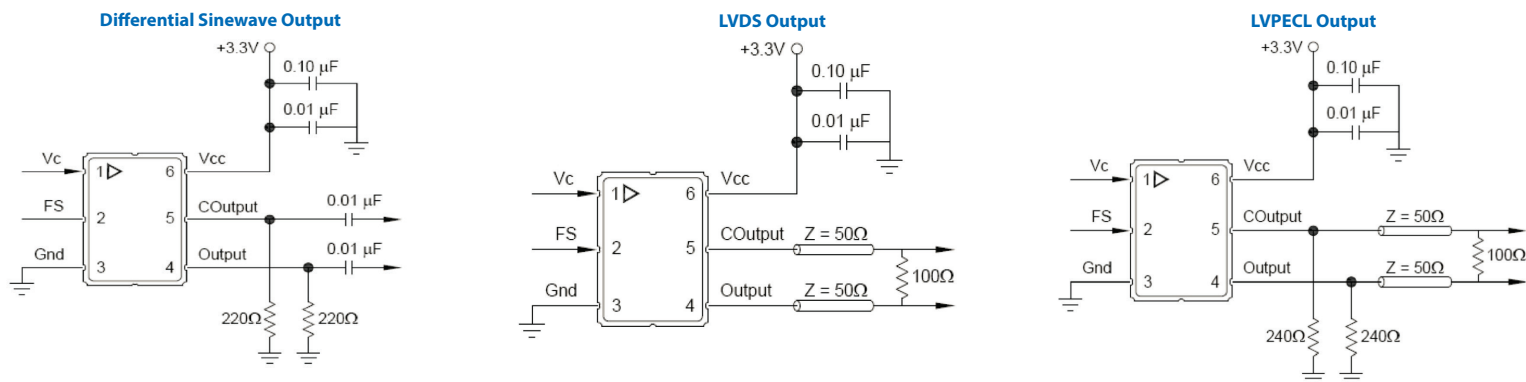
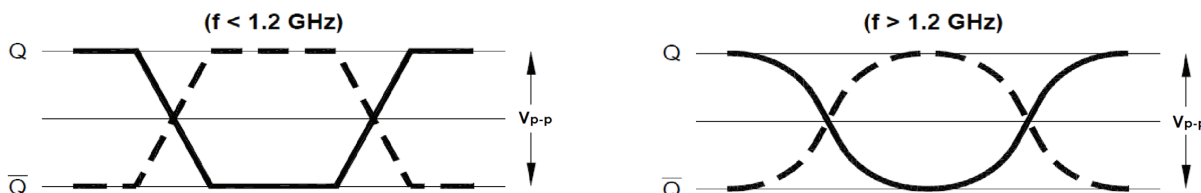


Figure 4. Performance Characteristics @ 2.2 GHz

## Output Load Configuration



### Output Waveform Definition



## Reliability

VI qualification includes aging at various extreme temperatures, shock and vibration, temperature cycling, and IR reflow simulation. The VS-708 family is capable of meeting the following qualification tests:

Environmental Compliance	
Parameter	Conditions
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Solderability	MIL-STD-883, Method 2003
Gross and Fine Leak	MIL-STD-883, Method 1014
Resistance to Solvents	MIL-STD-883, Method 2016
Moisture Sensitivity Level	IPC/JEDEC J-STD-020, MSL1

### Handling Precautions

Although ESD protection circuitry has been designed into the VS-708 proper precautions should be taken when handling and mounting. VI employs a Human Body Model (HBM), a Charged Device Model (CDM), and a Machine Model (MM) for ESD susceptibility testing and design protection evaluation.

ESD Ratings		
Model	Minimum	Conditions
Human Body Model	2000 V	MIL-STD 883, Method 3015
Charged Device Model	1000 V	JEDEC, JESD22-C101
Machine Model	200 V	JEDEC, JESD22-A115-A

Reflow Profile (IPC/JEDEC J-STD-020)		
Parameter	Symbol	Value
PreHeat Time	$t_s$	60 s min., 180 s max.
Ramp Up	$R_{UP}$	3°C / s max.
Time Above 217°C	$t_L$	60 s min., 150 s max.
Time To Peak Temperature	$t_{AMB-P}$	480 s max.
Time At 260°C	$t_P$	20 s min., 40 s max.
Ramp Down	$R_{DN}$	6°C / s max.

The device has been qualified to meet the JEDEC standard for Pb-free assembly. The temperatures and time intervals listed are based on the Pb-free small body requirements. The temperatures refer to the topside of the package, measured on the package body surface. The VS-708 device is hermetically sealed so an aqueous wash is not an issue.

Terminal Plating: Electroless Au > 1.50  $\mu\text{m}$  over  
Electroless Ni > 1.90  $\mu\text{m}$

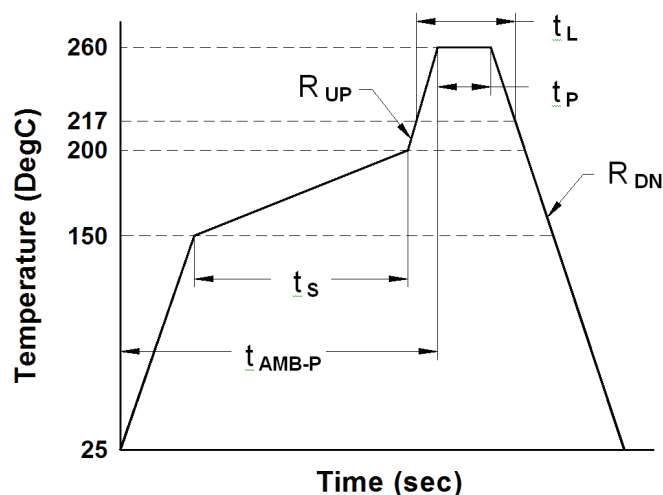
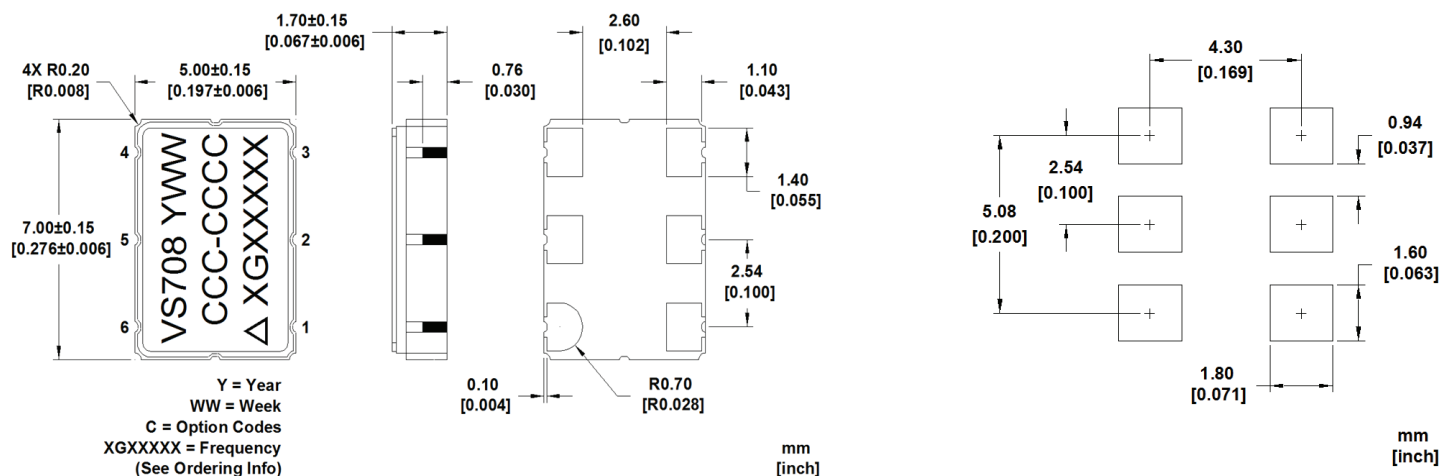


Figure 5. Recommended Reflow Profile

# Outline Drawing & Pad Layout



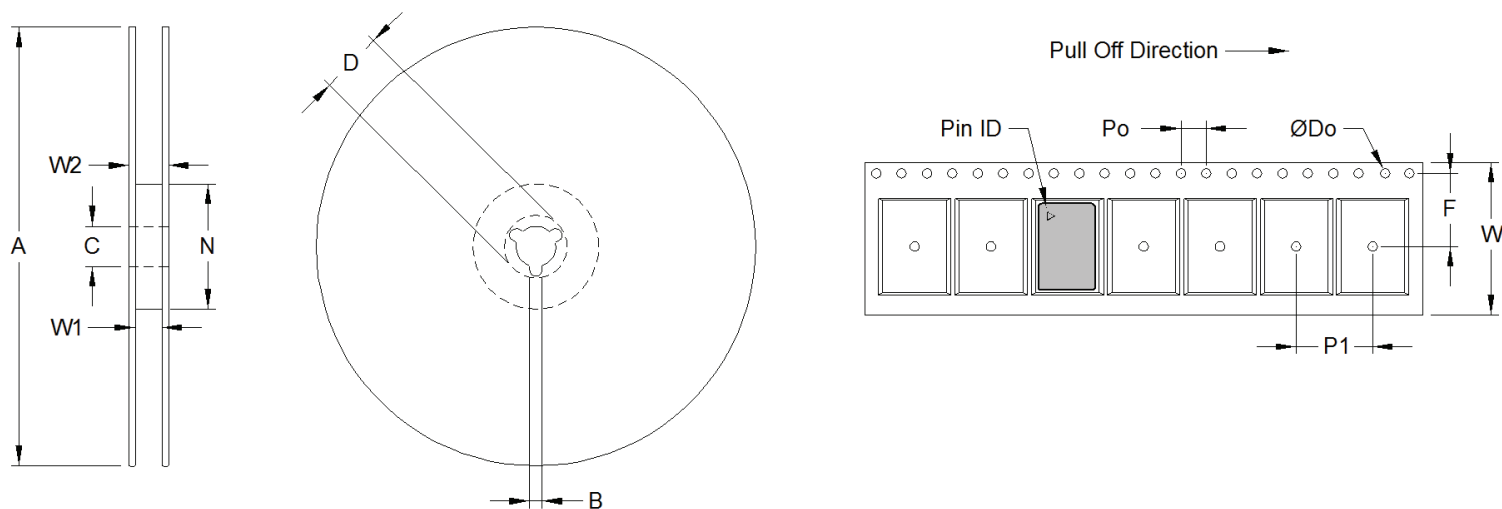
Pin Out		
Pin	Symbol	Function
1	V <sub>c</sub>	Control Voltage
2	OE	Output Enable
3	GND	Case and Electrical Ground
4	Output	Output
5	COutput	Complementary Output
6	V <sub>cc</sub>	Power Supply Voltage

Pin Out			
Option	OE	Voltage Range	Result
A	H	(5V <sub>cc</sub> / 6) to V <sub>cc</sub>	OE
	M	(V <sub>cc</sub> / 2) ± 15% (V <sub>cc</sub> / 2)	OS
	L	Gnd to (V <sub>cc</sub> / 6)	OD
B	H	(5V <sub>cc</sub> / 6) to V <sub>cc</sub>	OD
	M	(V <sub>cc</sub> / 2) ± 15% (V <sub>cc</sub> / 2)	OS
	L	Gnd to (V <sub>cc</sub> / 6)	OE

Floating OE Always Results In Outputs Enabled

OE = Outputs Enabled  
 OS = Outputs Set (Output = H, COutput = L)  
 OD = Outputs Disabled

## Tape and Reel (EIA-481-2-A)



Tape Dimensions (mm)						Reel Dimensions (mm)							
Dimension	W	F	Do	Po	P1	A	B	C	D	N	W1	W2	#Per Reel
Tolerance	Typ.	Typ.	Typ.	Typ.	Typ.	Typ.	Min.	Typ.	Min.	Min.	Typ.	Max.	
VS-708	16	7.5	1.5	4	8	178	1.5	13	20.2	50	16.4	22.4	200

## Ordering Information

Standard Frequencies (MHz)						
873.515420	983.040000	993.409690				

Standard Frequencies (GHz)						
1.1950000	1.22880000	1.47456000	1.74703084	1.8750000	1.96608000	1.98681938

Other Frequencies Available Upon Request

## Ordering Information

# VS-708 - E G U - K A A N - xGxxxxxxxx

**Product Family**

VS: VCSO

**Package**

708: 5.0 x 7.0 x 1.8 mm<sup>3</sup>

**Supply Voltage**

E: 3.3 V

**Output**

C: LVPECL\*  
G: Differential Sinewave \*

**Operating Temperature**

U: 0°C to 85°C  
E: -40°C to 85°C

**Absolute Pull Range**

K: ± 50 ppm

**Frequency (See Above)**

600M000000 - 2G30000000

**Factory Use**

N: N/A

**Oscillator Gain**

A: Standard

**Enable Logic (Float Condition)**

A: H=OE, M=OS, L=OD (OE)  
B: H=OD, M=OS, L=OE (OE)

Example: **VS-708-EGE-KAAN-2G30000000**

\*LVPECL and LVDS available for  $f_N < 1.2\text{GHz}$ ,  
Differential Sinewave available for  $f_N \geq 1.2\text{GHz}$

Revision History		
Date	Approved	Description
19Jun2015	TM	Generation of development specification
18Nov2015	MK	Product image changed
16Feb2016	MK	Output type LVPECL added
13May2016	MK	Datasheet layout changed

## For Additional Information, Please Contact

### USA:

Vectron International  
267 Lowell Road, Suite 102  
Hudson, NH 03051  
Tel: 1.888.328.7661  
Fax: 1.888.329.8328

### Europe:

Vectron International  
Potsdamer Strasse, D-14513  
Teltow, Germany  
Tel: +49 (0) 3328.4784.17  
Fax: +49 (0) 3328.4784.30

### Asia:

Vectron International  
68 Yin Cheng Road (C), 22nd Floor  
One LuJiaZui  
Pudong, Shanghai, 200120 China  
Tel: +86.21.6194.6886  
Fax: +86.21.6194.6699

### Disclaimer

Vectron International reserves the right to make changes to the product(s) and or information contained herein without notice. No liability is assumed as a result of their use or application. No rights under any patent accompany the sale of any such product(s) or information.